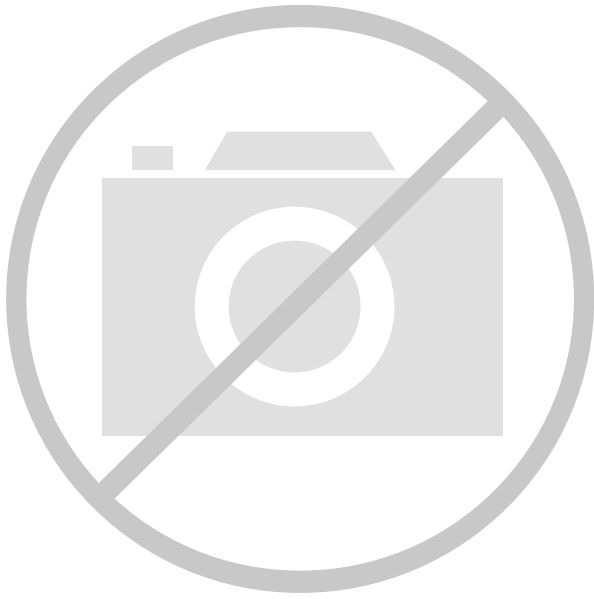




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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	960
Number of Logic Elements/Cells	7680
Total RAM Bits	131072
Number of I/O	150
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	196-VFBGA, CSPBGA
Supplier Device Package	196-CSPBGA (8x8)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/ice65l08f-lcb196i

Programmable Logic Block (PLB)

Generally, a logic design for an iCE65 component is created using a high-level hardware description language such as Verilog or VHDL. The Lattice Semiconductor development software then synthesizes the high-level description into equivalent functions built using the programmable logic resources within each iCE65 device. Both sequential and combinational functions are constructed from an array of Programmable Logic Blocks (PLBs). Each PLB contains eight Logic Cells (LCs), as pictured in Figure 4, and share common control inputs, such as clocks, reset, and enable controls.

PLBs are connected to one another and other logic functions using the rich Programmable Interconnect resources.

Logic Cell (LC)

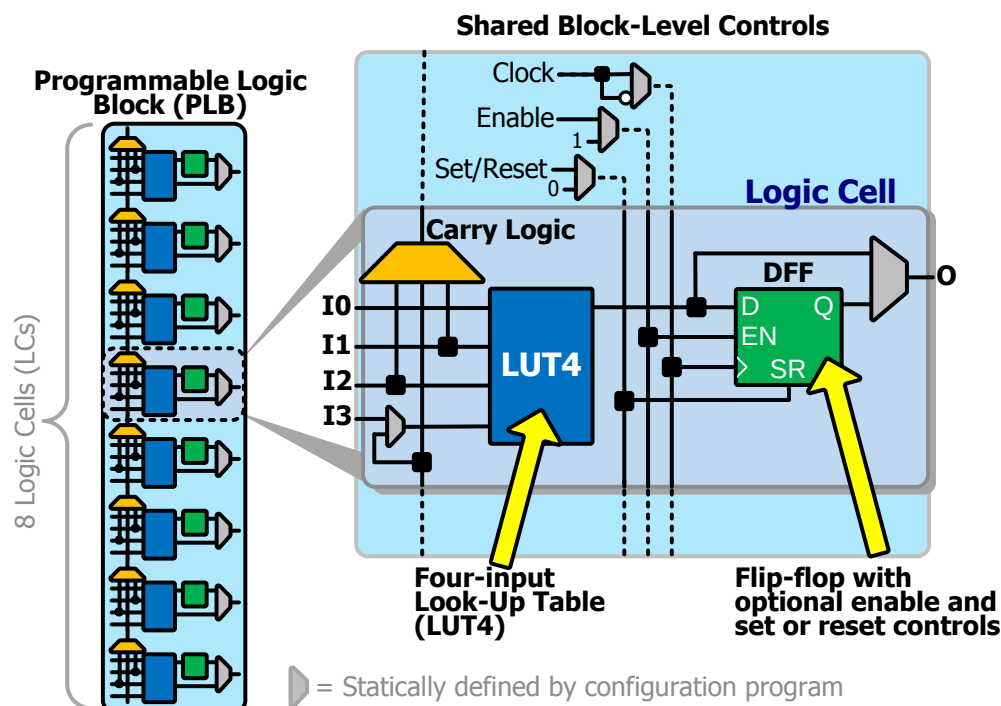
Each iCE65 device contains thousands of Logic Cells (LCs), as listed in Table 1. Each Logic Cell includes three primary logic elements, shown in Figure 4.

- A four-input **Look-Up Table (LUT4)** builds any combinational logic function, of any complexity, of up to four inputs. Similarly, the LUT4 element behaves as a 16x1 Read-Only Memory (ROM). Combine and cascade multiple LUT4s to create wider logic functions.

Figure 4: Programmable Logic Block and Logic Cell

- A **'D'-style Flip-Flop (DFF)**, with an optional clock-enable and reset control input, builds sequential logic functions. Each DFF also connects to a global reset signal that is automatically asserted immediately following device configuration.
- **Carry Logic** boosts the logic efficiency and performance of arithmetic functions, including adders, subtractors, comparators, binary counters and some wide, cascaded logic functions.

The output from a Logic Cell is available to all inputs to all eight Logic Cells within the Programmable Logic Block. Similarly, the Logic Cell output feeds into fabric to connect to other features on the iCE65 device.



Automatic Global Buffer Insertion, Manual Insertion

The iCEcube development software automatically assigns high-fanout signals to a global buffer. However, to manually insert a global buffer input/global buffer (GBIN/GBUF) combination, use the **SB_IO_GB** primitive. To insert just a global buffer (GBUF), use the **SB_GB** primitive.

Global Hi-Z Control

The global high-impedance control signal, GHIZ, connects to all I/O pins on the iCE65 device. This GHIZ signal is automatically asserted throughout the configuration process, forcing all user-I/O pins into their high-impedance state. Similarly, the PIO pins can be forced into their high-impedance state via the JTAG controller.

Global Reset Control

The global reset control signal connects to all PLB and PIO flip-flops on the iCE65 device. The global reset signal is automatically asserted throughout the configuration process, forcing all flip-flops to their defined wake-up state. For PLB flip-flops, the wake-up state is always reset, regardless of the PLB flip-flop primitive used in the application. See [Table 3](#) for more information.

The PIO flip-flops are always reset during configuration, although the output flip-flop can be inverted before leaving the iCE65 device, as shown in [Figure 11](#).

RAM

Each iCE65 device includes multiple high-speed synchronous RAM blocks (RAM4K), each 4Kbit in size. As shown in [Table 16](#) a single iCE65 integrates between 16 to 96 such blocks. Each RAM4K block is generically a 256-word deep by 16-bit wide, two-port register file, as illustrated in [Figure 17](#). The input and output connections, to and from a RAM4K block, feed into the programmable interconnect resources.

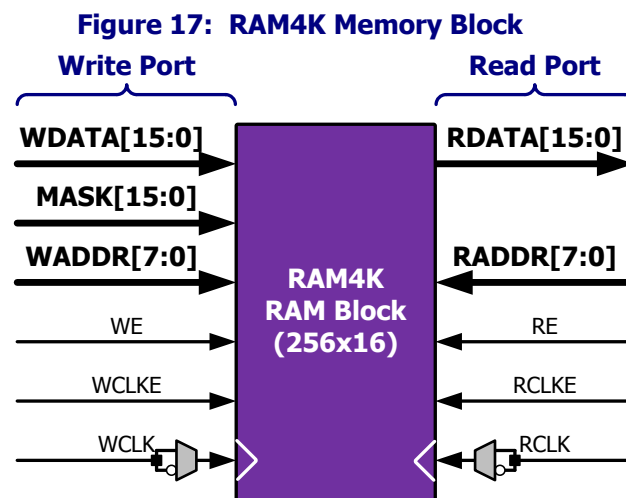


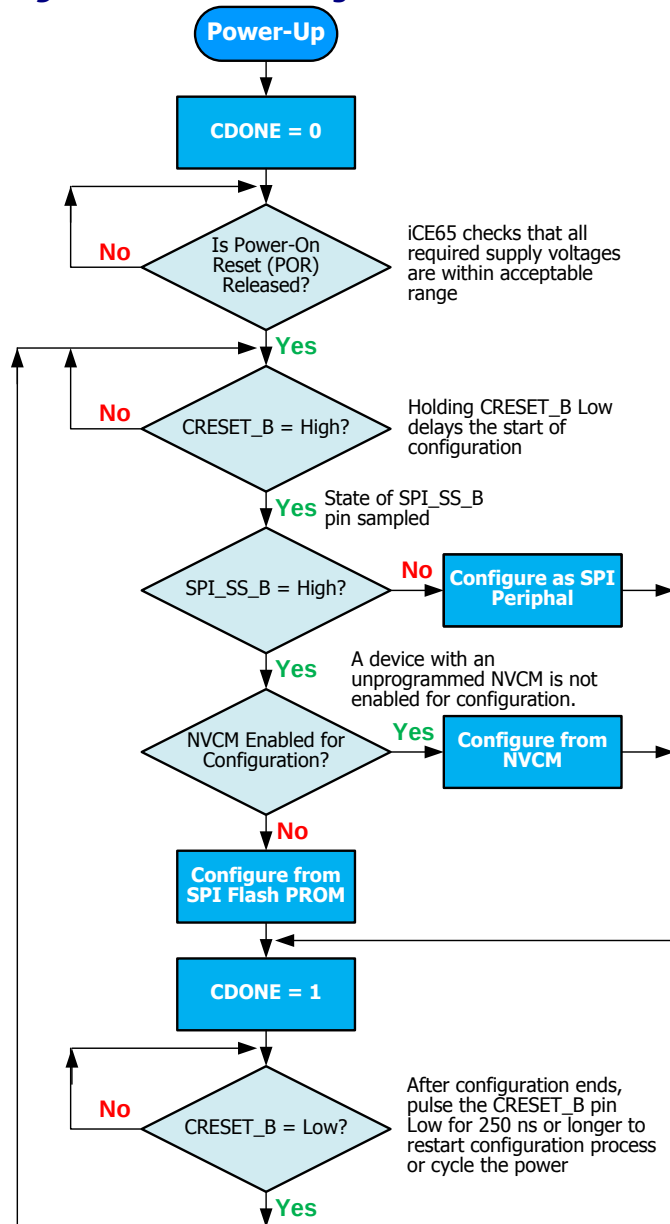
Table 16: RAM4K Blocks per Device

Device	RAM4K Blocks	Default Configuration	RAM Bits per Block	Block RAM Bits
iCE65L01	16	256 x 16	4K (4,096)	64K
iCE65L04	20			80K
iCE65L08	32			128K

Using programmable logic resources, a RAM4K block implements a variety of logic functions, each with configurable input and output data width.

- Random-access memory (RAM)
 - ◆ Single-port RAM with a common address, enable, and clock control lines
 - ◆ Two-port RAM with separate read and write control lines, address inputs, and enable

Figure 20: Device Configuration Control Flow



Configuration Image Size

Table 23 shows the number of memory bits required to configure an iCE65 device. Two values are provided for each device. The “Logic Only” value indicates the minimum configuration size, the number of bits required to configure only the logic fabric, leaving the RAM4K blocks uninitialized. The “Logic + RAM4K” column indicates the maximum configuration size, the number of bits to configure the logic fabric and to pre-initialize all the RAM4K blocks.

Table 21: iCE65 Configuration Image Size (Kbits)

Device	MINIMUM Logic Only (RAM4K not initialized)	MAXIMUM Logic + RAM4K (RAM4K pre-initialized)
iCE65L01	181 Kbits	245 Kbits*
iCE65L04	453 Kbits	533 Kbits
iCE65L08	929 Kbits	1,057 Kbits

* Note: only 14 of the 16 RAM4K Memory Blocks may be pre-initialized in the iCE65L01.

Nonvolatile Configuration Memory (NVCM)

All standard iCE65 devices have an internal, nonvolatile configuration memory (NVCM). The NVCM is large enough to program a complete iCE65 device, including initializing all RAM4K block locations (MAXIMUM column in Table 23). The NVCM memory also has very high programming yield due to extensive error checking and correction (ECC) circuitry.

The NVCM is ideal for cost-sensitive, high-volume production applications, saving the cost and board space associated with an external configuration PROM. Furthermore, the NVCM provides exceptional design security, protecting critical intellectual property (IP). The NVCM contents are entirely contained within the iCE65 device and are not readable once protected by the one-time programmable Security bits. Furthermore, there is no observable difference between a programmed or un-programmed memory cell using optical or electron microscopy.

The NVCM memory has a programming interface similar to a 25-series SPI serial Flash PROM. Consequently, it can be programmed using standard device programmers before or after circuit board assembly or programmed in-system from a microprocessor or other intelligent controller. NVCM programming requires VCCIO_1, Bank 1 voltage to be applied on power-up, at the same time as other voltage supplies.

Configuration Control Signals

The iCE65 configuration process is self-timed and controlled by a few internal signals and device I/O pins, as described in [Table 22](#).

Table 22: iCE65 Configuration Control Signals

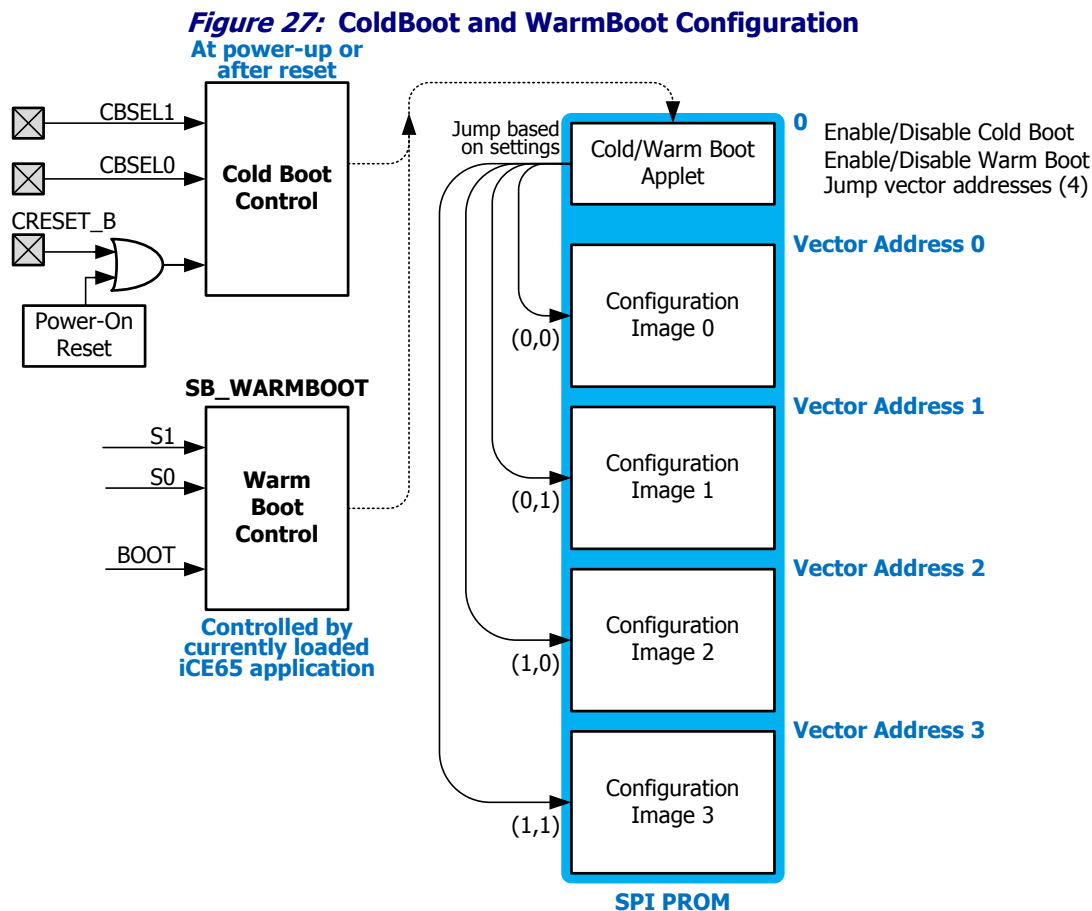
Signal Name	Direction	Description
POR	Internal control	Internal Power-On Reset (POR) circuit.
OSC	Internal control	Internal configuration oscillator.
CRESET_B	Input	Configuration Reset input. Active-Low. No internal pull-up resistor.
CDONE	Open-drain Output	Configuration Done output. Permanent, weak pull-up resistor to VCCIO_2.

The Power-On Reset circuit, [POR](#), automatically resets the iCE65 component to a known state during power-up (cold boot). The POR circuit monitors the relevant voltage supply inputs, as shown in [Figure 22](#). Once all supplies exceed their minimum thresholds, the configuration controller can start the configuration process.

The configuration controller begins configuring the iCE65 device, clocked by the [Internal Oscillator](#), OSC. The OSC oscillator continues controlling configuration unless the iCE65 device is configured using the [SPI Peripheral Configuration Interface](#).

Cold Boot Configuration Option

By default, the iCE65 FPGA is programmed with a single configuration image, either from internal NVCM memory, from an external SPI Flash PROM, or externally from a processor or microcontroller.



When self loading from NVCM or from an SPI Flash PROM, there is an additional configuration option called Cold Boot mode. When this option is enabled in the configuration bitstream, the iCE65 FPGA boots normally from power-on or a master reset (CRESET_B = Low pulse), but monitors the value on two PIO pins that are borrowed during configuration, as shown in Figure 27. These pins, labeled PIO2/CBSEL0 and PIO2/CBSEL1, tell the FPGA which of the four possible SPI configurations to load into the device. Table 30 provides the pin or ball locations for these pins.

- Load from initial location, either from NVCM or from address 0 in SPI Flash PROM. For Cold Boot or Warm Boot applications, the initial configuration image contains the cold boot/warm boot applet.
- Check if Cold Boot configuration feature is enabled in the bitstream.
 - ◆ If not enabled, FPGA configures normally.
 - ◆ If Cold Boot is enabled, then the FPGA reads the logic values on pins CBSEL[1:0]. The FPGA uses the value as a vector and then reads from the indicated vector address.
 - ◆ At the selected CBSEL[1:0] vector address, there is a starting address for the selected configuration image.
 - For SPI Flash PROMs, the new address is a 24-bit start address in Flash.
 - If the selected bitstream is in NVCM, then the address points to the internal NVCM.
- Using the new start address, the FPGA restarts reading configuration memory from the new location.

Table 31 describes how to maintain voltage compatibility for two interface scenarios. The easiest interface is when the Application Processor's (AP) I/O supply rail and the iCE65's SPI and VCCIO_2 bank supply rails all connect to the same voltage. The second scenario is when the AP's I/O supply voltage is greater than the iCE65's VCCIO_2 supply voltage.

Table 31: CRESET_B and CDONE Voltage Compatibility

Condition	CRESET_B			CDONE Pull-up	Requirement
	Direct	Open-Drain	Pull-up		
VCCIO_AP = VCC_SPI VCCIO_AP = VCCIO_2	OK	OK with pull-up	Required if using open-drain output	Recommended	AP can directly drive CRESET_B High and Low although an open-drain output recommended is if multiple devices control CRESET_B. If using an open-drain driver, the CRESET_B input must include a 10 kΩ pull-up resistor to VCCIO_2. The 10 kΩ pull-up resistor to AP_VCCIO is also recommended.
AP_VCCIO > VCCIO_2	N/A	Required, requires pull-up	Required	Required	The AP must control CRESET_B with an open-drain output, which requires a 10 kΩ pull-up resistor to VCCIO_2. The 10 kΩ pull-up resistor to AP_VCCIO is required.

JTAG Boundary Scan Port

Overview

Each iCE65 device includes an IEEE 1149.1-compatible JTAG boundary-scan port. The port supports printed-circuit board (PCB) testing and debugging. It also provides an alternate means to configure the iCE65 device.

Signal Connections

The JTAG port connections are listed in Table 32.

Table 32: iCE65 JTAG Boundary Scan Signals

Signal Name	Direction	Description
TDI	Input	Test Data Input. Must be tied off to GND when unused. (no pull-up resistor)*
TMS	Input	Test Mode Select. Must be tied off to GND when unused. (no pull-up resistor)*
TCK	Input	Test Clock. Must be tied off to GND when unused. (no pull-up resistor)*
TDO	Output	Test Data Output.
TRST_B	Input	Test Reset, active Low. Must be Low during normal device operation. Must be High to enable JTAG operations.*

* Must be tied off to GND or VCCIO_1, else VCCIO_1 draws current.

Table 33 lists the ball/pin numbers for the JTAG interface by package code. The JTAG interface is available in select package types. The JTAG port is located in I/O Bank 1 along the right edge of the iCE65 device and powered by the VCCIO_1 supply inputs. Consequently, the JTAG interface uses the associated I/O standards for I/O Bank 1.

Table 33: JTAG Interface Ball/Pin Numbers by Package

JTAG Interface	VQ100	CB132	CB196	CB284
TDI	N/A	M12	M12	T16
TMS		P14	P14	V18
TCK		L12	L12	R16
TDO		N14	N14	U18
TRST_B		M14	M14	T18

Pinout Table

Table 37 provides a detailed pinout table for the CB81 package. Pins are generally arranged by I/O bank, then by ball function.

Table 37: iCE65 CB81 Chip-scale BGA Pinout Table

Ball Function	Ball Number	Pin Type	Bank
PIO0	A2	PIO	0
PIO0	A3	PIO	0
GBIN0/PIO0	A4	GBIN	0
PIO0	A7	PIO	0
PIO0	A8	PIO	0
PIO0	B4	PIO	0
PIO0	B5	PIO	0
PIO0	B6	PIO	0
PIO0	B7	PIO	0
PIO0	B8	PIO	0
PIO0	C4	PIO	0
PIO0	C5	PIO	0
PIO0	C6	PIO	0
PIO0	D4	PIO	0
PIO0	D5	PIO	0
GBIN1/PIO0	D6	GBIN	0
PIO0	E6	PIO	0
VCCIO_0	A6	VCCIO	0
PIO1	C7	PIO	1
PIO1	C8	PIO	1
PIO1	C9	PIO	1
PIO1	D7	PIO	1
PIO1	D8	PIO	1
PIO1	E7	PIO	1
PIO1	E8	PIO	1
PIO1	E9	PIO	1
PIO1	F6	PIO	1
GBIN2/PIO1	F7	GBIN	1
GBIN3/PIO1	F8	GBIN	1
PIO1	F9	PIO	1
PIO1	G6	PIO	1
PIO1	G7	PIO	1
PIO1	G8	PIO	1
PIO1	G9	PIO	1
VCCIO_1	D9	VCCIO	1
CDONE	H6	CONFIG	2
CRESET_B	J6	CONFIG	2
PIO2	G3	PIO	2
PIO2	G4	PIO	2
PIO2/CBSEL0	G5	PIO	2
PIO2	H3	PIO	2
GBIN5/PIO2	H4	PIO	2
PIO2/CBSEL1	H5	PIO	2
PIO2	J2	PIO	2
GBIN4/PIO2	J3	PIO	2
VCCIO_2	J4	PIO	2

iCE65 Ultra Low-Power mobileFPGA™ Family

Pin Function	Pin Number	Type	Bank
PIO2	28	PIO	2
PIO2	29	PIO	2
PIO2	30	PIO	2
PIO2	iCE65L01: 34 iCE65L04: 36	PIO	2
PIO2	37	PIO	2
PIO2	40	PIO	2
PIO2/CBSEL0	41	PIO	2
PIO2/CBSEL1	42	PIO	2
VCCIO_2	31	VCCIO	2
VCCIO_2	38	VCCIO	2
PIO3/DP00A	1	PIO/DPIO	3
PIO3/DP00B	2	PIO/DPIO	3
PIO3/DP01A	3	PIO/DPIO	3
PIO3/DP01B	4	PIO/DPIO	3
PIO3/DP02A	7	PIO/DPIO	3
PIO3/DP02B	8	PIO/DPIO	3
PIO3/DP03A	9	PIO/DPIO	3
PIO3/DP03B	10	PIO/DPIO	3
PIO3/DP04A	12	PIO/DPIO	3
GBIN7/PIO3/DP04B	13	GBIN/DPIO	3
GBIN6/PIO3/DP05A	15	GBIN/DPIO	3
PIO3/DP05B	16	PIO/DPIO	3
PIO3/DP06A	18	PIO/DPIO	3
PIO3/DP06B	19	PIO/DPIO	3
PIO3/DP07A	20	PIO/DPIO	3
PIO3/DP07B	21	PIO/DPIO	3
PIO3/DP08A	24	PIO/DPIO	3
PIO3/DP08B	25	PIO/DPIO	3
VCCIO_3	6	VCCIO	3
VCCIO_3	14	VCCIO	3
VCCIO_3	22	VCCIO	3
PIOS/SPI_SO	45	SPI	SPI
PIOS/SPI_SI	46	SPI	SPI
PIOS/SPI_SCK	48	SPI	SPI
PIOS/SPI_SS_B	49	SPI	SPI
SPI_VCC	50	SPI	SPI
GND	5	GND	GND
GND	17	GND	GND
GND	23	GND	GND
GND	32	GND	GND
GND	39	GND	GND
GND	47	GND	GND
GND	55	GND	GND
GND	70	GND	GND
GND	84	GND	GND
GND	98	GND	GND
VCC	11	VCC	VCC
VCC	35	VCC	VCC

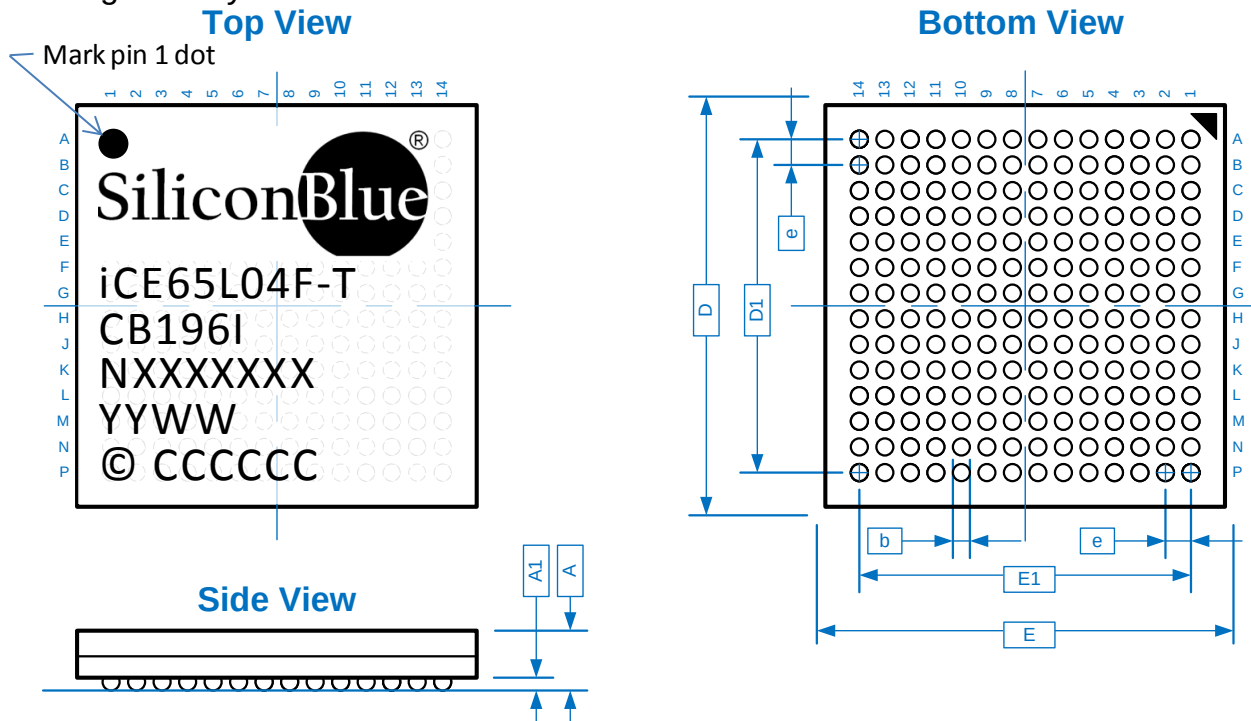
iCE65 Ultra Low-Power mobileFPGA™ Family

Ball Function	Ball Number	Pin Type	Bank
PIO1	H12	PIO	1
PIO1	J11	PIO	1
PIO1	J12	PIO	1
PIO1	K11	PIO	1
PIO1	K12	PIO	1
PIO1	K14	PIO	1
PIO1	L14	PIO	1
TCK	L12	JTAG	1
TDI	M12	JTAG	1
TDO	N14	JTAG	1
TMS	P14	JTAG	1
TRST_B	M14	JTAG	1
VCCIO_1	F9	VCCIO	1
VCCIO_1	H14	VCCIO	1
CDONE	M10	CONFIG	2
CRESET_B	L10	CONFIG	2
GBIN4/PIO2	P8	GBIN	2
GBIN5/PIO2	P7	GBIN	2
PIO2	L4	PIO	2
PIO2	L5	PIO	2
PIO2	L6	PIO	2
PIO2	L7	PIO	2
PIO2	L8	PIO	2
PIO2	M3	PIO	2
PIO2	M4	PIO	2
PIO2	M6	PIO	2
PIO2	M7	PIO	2
PIO2	M8	PIO	2
PIO2	M9	PIO	2
PIO2	P2	PIO	2
PIO2	P3	PIO	2
PIO2	P4	PIO	2
PIO2	P5	PIO	2
PIO2	P9	PIO	2
PIO2/CBSEL0	L9	PIO	2
PIO2/CBSEL1	P10	PIO	2
VCCIO_2	J9	PIO	2
VCCIO_2	M5	PIO	2
PIO3/DP00A	B1	DPIO	3
PIO3/DP00B	C1	DPIO	3
PIO3/DP01A	C3	DPIO	3
PIO3/DP01B	D3	DPIO	3
PIO3/DP02A	D4	DPIO	3
PIO3/DP02B	E4	DPIO	3
PIO3/DP03A	D1	DPIO	3
PIO3/DP03B	E1	DPIO	3
PIO3/DP04A	F4	DPIO	3
PIO3/DP04B	F3	DPIO	3
L01/L04: GBIN6/PIO3 L08: GBIN6/DP06A	H1	GBIN	3

Ball Function	Ball Number	Pin Type	Bank
L01/L04: GBIN7/PIO3 L08: GBIN7/DP05B	G1	GBIN	3
L01/L04: PIO3/DP05A L08: PIO3/DP05A	G3	DPIO	3
L01/L04: PIO3/DP05B L08: PIO3/DP11B	G4	DPIO	3
L01/L04: PIO3/DP06A L08: PIO3/DP06B	H3	DPIO	3
L01/L04: PIO3/DP06B L08: PIO3/DP11A	H4	DPIO	3
PIO3/DP07A	J3	DPIO	3
PIO3/DP07B	J1	DPIO	3
PIO3/DP08A	K3	DPIO	3
PIO3/DP08B	K4	DPIO	3
PIO3/DP09A	L1	DPIO	3
PIO3/DP09B	M1	DPIO	3
PIO3/DP10A	N1	DPIO	3
PIO3/DP10B	P1	DPIO	3
VCCIO_3	E3	VCCIO	3
VCCIO_3	J6	VCCIO	3
VCCIO_3	K1	VCCIO	3
PIOS/SPI_SO	M11	SPI	SPI
PIOS/SPI_SI	P11	SPI	SPI
PIOS/SPI_SCK	P12	SPI	SPI
PIOS/SPI_SS_B	P13	SPI	SPI
SPI_VCC	L11	SPI	SPI
GND	A9	GND	GND
GND	F1	GND	GND
GND	F7	GND	GND
GND	G7	GND	GND
GND	G8	GND	GND
GND	G9	GND	GND
GND	H6	GND	GND
GND	H7	GND	GND
GND	H8	GND	GND
GND	J8	GND	GND
GND	J14	GND	GND
GND	L3	GND	GND
GND	P6	GND	GND
VCC	F8	VCC	VCC
VCC	G6	VCC	VCC
VCC	H9	VCC	VCC
VCC	J4	VCC	VCC
VCC	J7	VCC	VCC
VPP_2V5	A14	VPP	VPP
VPP_FAST	A13	VPP	VPP

Figure 47:
(a) iCE65L04 CB196 Package Mechanical Drawing

CB196: 8 x8 mm, 196-ball, 0.5 mm ball-pitch, fully-populated, chip-scale ball grid array



Description	Symbol	Min.	Nominal	Max.	Units
Number of Ball Columns	X		14		Columns
Number of Ball Rows	Y		14		Rows
Number of Signal Balls	n		196		Balls
Body Size	X	E	7.90	8.00	mm
	Y	D	7.90	8.00	
Ball Pitch		e	—	0.50	
Ball Diameter		b	0.27	—	
Edge Ball Center to Center	X	E1	—	6.50	
	Y	D1	—	6.50	
Package Height		A	—	1.00	
Stand Off		A1	0.16	—	

Top Marking Format

Line	Content	Description
1	Logo	Logo
2	iCE65L04F	Part number
	-T	Power/Speed
3	CB196I	Package type
	ENG	Engineering
4	NXXXXXXX	Lot Number
5	YYWW	Date Code
6	© CCCCCC	Country

Thermal Resistance

Junction-to-Ambient θ_{JA} (°C/W)	
0 LFM	200 LFM
42	34

CB284 Chip-Scale Ball-Grid Array

The CB284 package, partially-populated 0.5 mm pitch, ball grid array simplifies PCB layout with empty ball rings.

Footprint Diagram

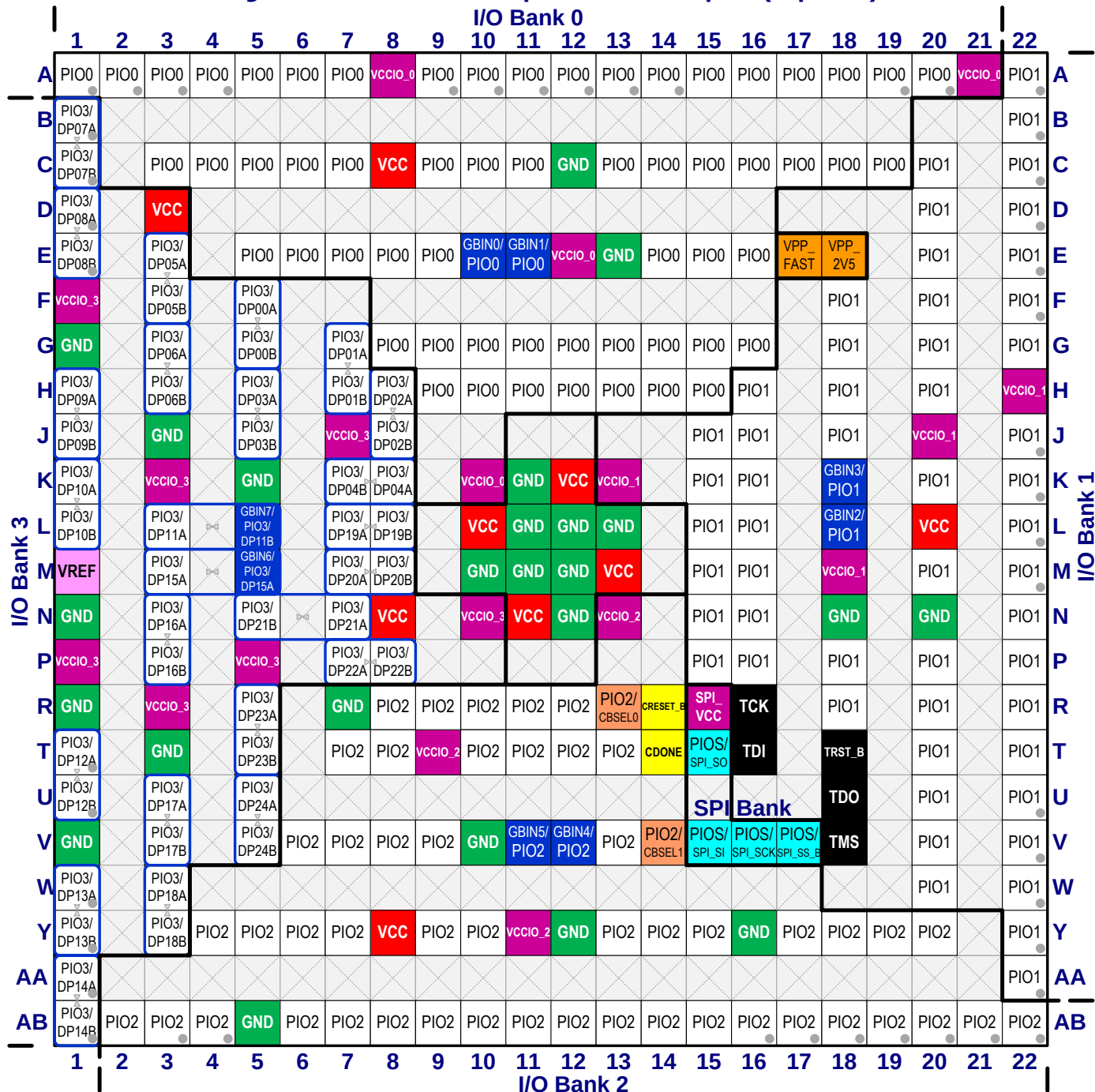
Figure 48 shows the CB284 chip-scale BGA footprint. The 8 x 8 mm CB132 package fits within the same ball pattern as the 12 x 12 mm CB284 package. In other words, the central 8 x 8 section of the CB284 footprint matches the CB132 footprint.

Figure 31 shows the conventions used in the diagram.

Also see Table 44 for a complete, detailed pinout for the 132-ball and 284-ball chip-scale BGA packages.

The signal pins are also grouped into the four I/O Banks and the SPI interface.

Figure 48: iCE65 CB284 Chip-Scale BGA Footprint (Top View)



Pinout Table

Table 44 provides a detailed pinout table for the two chip-scale BGA packages. Pins are generally arranged by I/O bank, then by ball function. The balls with a black circle (●) are unconnected balls (N.C.) for the iCE65L04 in the CB284 package. The CB132 package fits within the CB284 package footprint as shown in Figure 48. The right-most column shows which CB132 ball corresponds to the CB284.

The table also highlights the differential I/O pairs in I/O Bank 3.

Table 44: iCE65 CB284 Chip-scale BGA Pinout Table (with CB132 cross reference)

Ball Function	Ball Number	Pin Type by Device		Bank	CB132 Ball Equivalent
	iCE65L04 iCE65L08	iCE65L04	iCE65L08		
GBIN0/PIO0	E10	GBIN	GBIN	0	A6
GBIN1/PIO0	E11	GBIN	GBIN	0	A7
PIO0 (●)	A1	N.C.	PIO	0	—
PIO0 (●)	A2	N.C.	PIO	0	—
PIO0 (●)	A3	N.C.	PIO	0	—
PIO0 (●)	A4	N.C.	PIO	0	—
PIO0	A5	PIO	PIO	0	—
PIO0	A6	PIO	PIO	0	—
PIO0	A7	PIO	PIO	0	—
PIO0 (●)	A9	N.C.	PIO	0	—
PIO0 (●)	A10	N.C.	PIO	0	—
PIO0 (●)	A11	N.C.	PIO	0	—
PIO0 (●)	A12	N.C.	PIO	0	—
PIO0 (●)	A13	N.C.	PIO	0	—
PIO0	A15	PIO	PIO	0	—
PIO0	A16	PIO	PIO	0	—
PIO0	A17	PIO	PIO	0	—
PIO0	A18	PIO	PIO	0	—
PIO0 (●)	A14	N.C.	PIO	0	—
PIO0 (●)	A19	N.C.	PIO	0	—
PIO0 (●)	A20	N.C.	PIO	0	—
PIO0	C3	PIO	PIO	0	—
PIO0	C4	PIO	PIO	0	—
PIO0	C5	PIO	PIO	0	—
PIO0	C6	PIO	PIO	0	—
PIO0	C7	PIO	PIO	0	—
PIO0	C9	PIO	PIO	0	—
PIO0	C10	PIO	PIO	0	—
PIO0	C11	PIO	PIO	0	—
PIO0	C13	PIO	PIO	0	—
PIO0	C14	PIO	PIO	0	—
PIO0	C15	PIO	PIO	0	—
PIO0	C16	PIO	PIO	0	—
PIO0	C17	PIO	PIO	0	—
PIO0	C18	PIO	PIO	0	—
PIO0	C19	PIO	PIO	0	—
PIO0	E5	PIO	PIO	0	A1
PIO0	E6	PIO	PIO	0	A2
PIO0	E7	PIO	PIO	0	A3
PIO0	E8	PIO	PIO	0	A4
PIO0	E9	PIO	PIO	0	A5
PIO0	E14	PIO	PIO	0	A10

iCE65 Ultra Low-Power mobileFPGA™ Family

Ball Function	Ball Number	Pin Type by Device		Bank	CB132 Ball Equivalent
	iCE65L04 iCE65L08	iCE65L04	iCE65L08		
PIO0	E15	PIO	PIO	0	A11
PIO0	E16	PIO	PIO	0	A12
PIO0	G8	PIO	PIO	0	C4
PIO0	G9	PIO	PIO	0	C5
PIO0	G10	PIO	PIO	0	C6
PIO0	G11	PIO	PIO	0	C7
PIO0	G12	PIO	PIO	0	C8
PIO0	G13	PIO	PIO	0	C9
PIO0	G14	PIO	PIO	0	C10
PIO0	G15	PIO	PIO	0	C11
PIO0	G16	PIO	PIO	0	C12
PIO0	H9	PIO	PIO	0	D5
PIO0	H10	PIO	PIO	0	D6
PIO0	H11	PIO	PIO	0	D7
PIO0	H12	PIO	PIO	0	D8
PIO0	H13	PIO	PIO	0	D9
PIO0	H14	PIO	PIO	0	D10
PIO0	H15	PIO	PIO	0	D11
VCCIO_0	A8	VCCIO	VCCIO	0	—
VCCIO_0	A21	VCCIO	VCCIO	0	—
VCCIO_0	E12	VCCIO	VCCIO	0	A8
VCCIO_0	K10	VCCIO	VCCIO	0	F6
GBIN2/PIO1	L18	GBIN	GBIN	1	G14
GBIN3/PIO1	K18	GBIN	GBIN	1	F14
PIO1 (●)	A22	N.C.	PIO	1	—
PIO1 (●)	AA22	N.C.	PIO	1	—
PIO1 (●)	B22	N.C.	PIO	1	—
PIO1	C20	PIO	PIO	1	—
PIO1 (●)	C22	N.C.	PIO	1	—
PIO1	D20	PIO	PIO	1	—
PIO1 (●)	D22	N.C.	PIO	1	—
PIO1	E20	PIO	PIO	1	—
PIO1 (●)	E22	N.C.	PIO	1	—
PIO1	F18	PIO	PIO	1	B14
PIO1	F20	PIO	PIO	1	—
PIO1 (●)	F22	N.C.	PIO	1	—
PIO1	G18	PIO	PIO	1	C14
PIO1	G20	PIO	PIO	1	—
PIO1	G22	PIO	PIO	1	—
PIO1	H16	PIO	PIO	1	D12
PIO1	H18	PIO	PIO	1	D14
PIO1	H20	PIO	PIO	1	—
PIO1	J15	PIO	PIO	1	E11
PIO1	J16	PIO	PIO	1	E12
PIO1	J18	PIO	PIO	1	E14
PIO1 (●)	J22	N.C.	PIO	1	—
PIO1	K15	PIO	PIO	1	F11
PIO1	K16	PIO	PIO	1	F12
PIO1	K20	PIO	PIO	1	—
PIO1 (●)	K22	N.C.	PIO	1	—

iCE65 Ultra Low-Power mobileFPGA™ Family

iCE65L04 Pad Name	DiePlus				Pad	X (μm)	Y (μm)
	VQ100	CB132	CB196	CB284			
PIO1_24	—	—	G11	F20	167	3,712.80	1,812.00
PIO1_25	—	—	F11	E20	168	3,610.80	1,847.00
PIO1_26	—	—	E10	D20	169	3,712.80	1,882.00
PIO1_27	—	—	E14	C20	170	3,610.80	1,917.00
GND	—	G8	G8	L12	171	3,712.80	1,952.00
GND	—	—	—	—	172	3,610.80	1,987.00
PIO1_28	—	—	F12	G22	173	3,712.80	2,022.00
PIO1_29	—	G12	D14	L16	174	3,610.80	2,057.00
PIO1_30	64	G11	E13	L15	175	3,712.80	2,092.00
PIO1_31	65	F12	C14	K16	176	3,610.80	2,127.00
VCC	—	—	K13	L20	177	3,712.80	2,162.00
VCC	—	—	—	—	178	3,610.80	2,197.00
PIO1_32	66	E14	E11	J18	179	3,712.80	2,232.00
PIO1_33	—	F11	C13	K15	180	3,610.80	2,267.00
VCCIO_1	67	F9	F9	K13	181	3,712.80	2,302.00
VCCIO_1	—	—	—	—	182	3,610.80	2,337.00
PIO1_34	68	E12	E12	J16	183	3,712.80	2,377.00
PIO1_35	69	D14	B14	H18	184	3,610.80	2,427.00
GND	70	G9	G9	L13	185	3,712.80	2,477.00
PIO1_36	71	E11	B13	J15	186	3,610.80	2,527.00
PIO1_37	72	D12	D12	H16	187	3,712.80	2,577.00
PIO1_38	73	C14	C12	G18	188	3,610.80	2,627.00
PIO1_39	74	B14	D11	F18	189	3,712.80	2,677.00
VPP_2V5	75	A14	A14	E18	190	3,610.80	2,739.68
VPP_FAST	76	A13	A13	E17	191	3,097.00	2,962.80
VCC	77	F8	F8	K12	192	2,997.00	2,860.80
VCC	77	F8	F8	K12	193	2,947.00	2,962.80
PIO0_00	78	A12	C11	E16	194	2,897.00	2,860.80
PIO0_01	—	C12	—	G16	195	2,847.00	2,962.80
PIO0_02	79	A11	A12	E15	196	2,797.00	2,860.80
PIO0_03	80	C11	B11	G15	197	2,747.00	2,962.80
PIO0_04	—	D11	—	H15	198	2,697.00	2,860.80
PIO0_05	81	A10	D10	E14	199	2,647.00	2,962.80
PIO0_06	82	C10	A11	G14	200	2,612.00	2,860.80
PIO0_07	83	D10	D9	H14	201	2,577.00	2,962.80
GND	84	A9	H6	E13	202	2,542.00	2,860.80
GND	—	—	—	—	203	2,507.00	2,962.80
PIO0_08	85	C9	C10	G13	204	2,472.00	2,860.80
PIO0_09	86	D9	A10	H13	205	2,437.00	2,962.80
PIO0_10	87	C8	B10	G12	206	2,402.00	2,860.80
PIO0_11	—	D8	E9	H12	207	2,367.00	2,962.80
PIO0_12	—	—	—	A18	208	2,332.00	2,860.80
PIO0_13	—	—	—	A17	209	2,297.00	2,962.80
PIO0_14	—	—	—	A16	210	2,262.00	2,860.80
PIO0_15	—	—	—	A15	211	2,227.00	2,962.80
VCCIO_0	88	A8	A8	E12	212	2,192.00	2,860.80
VCCIO_0	—	—	—	—	213	2,157.00	2,962.80

iCE65 Ultra Low-Power mobileFPGA™ Family

iCE65L08 Pad Name	Available Packages		DiePlus		
	CB196	CB284	Pad	X (μm)	Y (μm)
PIO3_44/DP22A	M1	U3	86	231.735	777.67
PIO3_45/DP22B	M2	V3	87	129.735	732.67
PIO3_46/DP23A	N1	U5	88	231.735	687.67
PIO3_47/DP23B	N2	V5	89	129.735	642.67
PIO3_48/DP24A	—	W3	90	231.735	597.67
PIO3_49/DP24B	—	Y3	91	129.735	552.665
PIO2_00	P1	AB2	92	510.0	139.5
PIO2_01	M3	R8	93	560.0	37.5
PIO2_02	P2	Y4	94	610.0	139.5
GND	P6	AB5	95	660.0	37.5
GND	—	—	96	710.0	139.5
PIO2_03	M4	T7	97	760.0	37.5
PIO2_04	N3	AB3	98	810.0	139.5
PIO2_05	—	R9	99	859.3	37.5
PIO2_06	—	Y5	100	910.0	139.5
PIO2_07	L4	T8	101	960.0	37.5
PIO2_08	P3	V6	102	1,012.5	139.5
VCCIO_2	M5	T9	103	1,047.5	37.5
VCCIO_2	—	—	104	1,082.5	139.5
PIO2_09	P4	R10	105	1,117.5	37.5
PIO2_10	N4	AB4	106	1,152.5	139.5
GND	H8	V10	107	1,187.5	37.5
GND	—	—	108	1,222.5	139.5
PIO2_11	K5	V7	109	1,257.5	37.5
PIO2_12	P5	Y7	110	1,292.5	139.5
PIO2_13	—	V9	111	1,327.5	37.5
PIO2_14	—	Y6	112	1,362.5	139.5
PIO2_15	—	AB7	113	1,397.5	37.5
PIO2_16	—	AB6	114	1,432.5	139.5
PIO2_17	L5	Y9	115	1,467.5	37.5
PIO2_18	N5	V8	116	1,502.3	139.5
GND	P6	N12	117	1,537.3	37.5
GND	—	—	118	1,572.5	139.5
PIO2_19	N6	AB8	119	1,607.5	37.5
PIO2_20	K6	AB9	120	1,642.5	139.5
VCC	J7	Y8	121	1,677.5	37.5
VCC	—	—	122	1,712.5	139.5
PIO2_21	L6	T10	123	1,747.5	37.5
PIO2_22	M6	AB10	124	1,782.5	139.5
PIO2_23	—	AB11	125	1,817.5	37.5
PIO2_24	—	AB12	126	1,852.5	139.5
PIO2_25	L7	Y10	127	1,887.5	37.5
PIO2_26	P7	AB13	128	1,922.5	139.5
PIO2_27	K7	AB14	129	1,957.5	37.5
VCCIO_2	N10	Y11	130	1,992.5	139.5
VCCIO_2	—	—	131	2,027.5	37.5

iCE65 Ultra Low-Power mobileFPGA™ Family

iCE65L08 Pad Name	Available Packages		DiePlus		
	CB196	CB284	Pad	X (μm)	Y (μm)
GND	F7	E13	270	3,216.98	4,054.5
GND	—	—	271	3,166.98	4,156.5
PIO0_08	D9	E15	272	3,116.98	4,054.5
PIO0_09	C10	G14	273	3,064.48	4,156.5
PIO0_10	A10	A20	274	3,029.48	4,054.5
PIO0_11	B10	H13	275	2,994.48	4,156.5
PIO0_12	—	A19	276	2,959.48	4,054.5
PIO0_13	E9	G13	277	2,924.48	4,156.5
PIO0_14	—	C16	278	2,889.48	4,054.5
PIO0_15	—	E14	279	2,854.48	4,156.5
VCCIO_0	F6	E12	280	2,819.48	4,054.5
VCCIO_0	—	—	281	2,784.48	4,156.5
PIO0_16	—	A18	282	2,749.48	4,054.5
PIO0_17	—	A17	283	2,714.48	4,156.5
PIO0_18	C9	C15	284	2,679.48	4,054.5
PIO0_19	—	A16	285	2,644.48	4,156.5
PIO0_20	B9	C14	286	2,609.48	4,054.5
PIO0_21	—	H12	287	2,574.48	4,156.5
PIO0_22	D8	A15	288	2,539.48	4,054.5
PIO0_23	C8	H11	289	2,504.48	4,156.5
PIO0_24	E8	C13	290	2,469.48	4,054.5
PIO0_25	—	A14	291	2,434.48	4,156.5
GND	B12	C12	292	2,399.48	4,054.5
GND	—	—	293	2,364.48	4,156.5
PIO0_26	B8	A13	294	2,329.48	4,054.5
PIO0_27	D7	A12	295	2,294.48	4,156.5
PIO0_28	—	C11	296	2,259.48	4,054.5
GBIN1/PIO0_29	E7	E11	297	2,224.48	4,156.5
GBIN0/PIO0_30	A7	E10	298	2,189.48	4,054.5
PIO0_31	—	G12	299	2,154.48	4,156.5
VCCIO_0	A8	A8	300	2,119.48	4,054.5
VCCIO_0	—	—	301	2,084.48	4,156.5
PIO0_32	C7	A11	302	2,049.48	4,054.5
PIO0_33	—	G11	303	2,014.48	4,156.5
PIO0_34	E6	A10	304	1,979.48	4,054.5
PIO0_35	—	C10	305	1,944.48	4,156.5
VCC	B7	C8	306	1,909.48	4,054.5
VCC	—	—	307	1,874.48	4,156.5
PIO0_36	—	A9	308	1,839.48	4,054.5
PIO0_37	A6	A7	309	1,804.48	4,156.5
PIO0_38	B6	C9	310	1,769.48	4,054.5
PIO0_39	A5	A6	311	1,734.48	4,156.5
GND	G7	K11	312	1,699.48	4,054.5
GND	—	—	313	1,664.48	4,156.5
PIO0_40	D6	E9	314	1,629.48	4,054.5
PIO0_41	C6	G10	315	1,594.48	4,156.5

iCE65L08 Pad Name	Available Packages		DiePlus		
	CB196	CB284	Pad	X (μm)	Y (μm)
PI00_42	C5	A5	316	1,559.48	4,054.5
PI00_43	B5	G9	317	1,524.48	4,156.5
PI00_44	A4	A3	318	1,489.48	4,054.5
PI00_45	—	A4	319	1,454.48	4,156.5
PI00_46	—	A2	320	1,419.48	4,054.5
PI00_47	—	C7	321	1,384.48	4,156.5
PI00_48	—	C6	322	1,331.98	4,054.5
VCCIO_0	A8	K10	323	1,281.98	4,156.5
VCCIO_0	—	—	324	1,231.98	4,054.5
PI00_49	—	E8	325	1,181.98	4,156.5
PI00_50	B4	A1	326	1,131.98	4,054.5
PI00_51	C4	E7	327	1,081.98	4,156.5
PI00_52	A3	C5	328	1,031.98	4,054.5
PI00_53	B3	E6	329	981.98	4,156.5
PI00_54	D5	C3	330	931.98	4,054.5
GND	A9	L11	331	881.98	4,156.5
GND	—	—	332	831.98	4,054.5
PI00_55	B2	G8	333	781.98	4,156.5
PI00_56	A2	C4	334	731.98	4,054.5
PI00_57	A1	H10	335	681.98	4,156.5
PI00_58	—	E5	336	631.98	4,054.5
PI00_59	—	H9	337	581.98	4,156.5

RAM4K Block

Table 56 provides timing information for the logic in a RAM4K block, which includes the paths shown in Figure 59.

Figure 59: RAM4K Timing Circuit

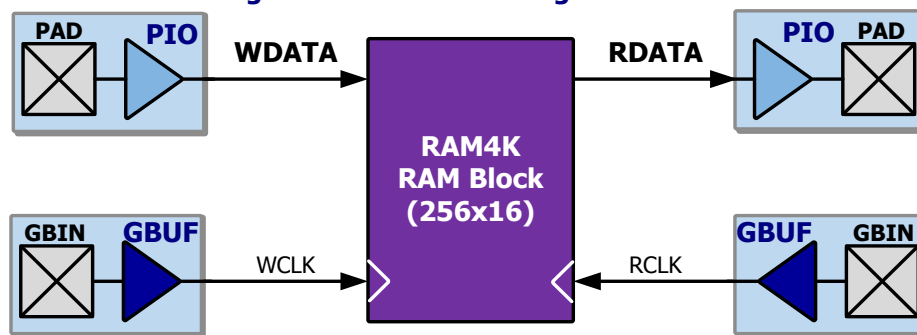


Table 56: Typical RAM4K Block Timing

Symbol	From	To	Device: ICE65	L01	L04, L08			Units
			Power/Speed Grade	−T	−L	−L	−T	
			Nominal VCC	1.2 V	1.0 V	1.2 V	1.2 V	
			Description	Typ.	Typ.	Typ.	Typ.	
Write Setup/Hold Time								
tSUWD	PIO input	GBIN input	Minimum write data setup time on PIO inputs before active clock edge on GBIN input, include interconnect delay.	0.6	3.1	1.7	0.8	ns
tHDWD	GBIN input	PIO input	Minimum write data hold time on PIO inputs after active clock edge on GBIN input, including interconnect delay.	0	0	0	0	ns
Read Clock-Output-Time								
tCKORD	RCLK clock input	PIO output	Clock-to-output delay from RCLK input pin, through RAM4K RDATA output flip-flop to PIO output pad, including interconnect delay.	5.6	17.1	9.1	7.3	ns
tGBCKRM	GBIN input	RCLK clock input	Global Buffer Input (GBIN) delay, though Global Buffer (GBUF) clock network to the RCLK clock input.	2.1	7.3	3.8	2.6	ns
Write and Read Clock Characteristics								
tRMWCKH	WCLK RCLK	WCLK RCLK	Write clock High time	0.54	1.14	0.54	0.54	ns
tRMWCKL			Write clock Low time	0.63	1.32	0.63	0.63	ns
tRMWCYC			Write clock cycle time	1.27	2.64	1.27	1.27	ns
FWMAX			Sustained write clock frequency	256	256	256	256	MHz

Table 60 provides various timing specifications for the SPI peripheral mode interface.

Table 60: SPI Peripheral Mode Timing

Symbol	From	To	Description		All Grades		Units
					Min.	Max.	
t_{CR_SCK}	CRESET_B	SPI_SCK	Minimum time from a rising edge on CRESET_B until the first SPI write operation, first SPI_SCK. During this time, the iCE65 FPGA is clearing its internal configuration memory	iCE65L01	800	—	µs
				iCE65L04	800		
				iCE65L08	1200		
t_{SUSPISI}	SPI_SI	SPI_SCK	Setup time on SPI_SI before the rising SPI_SCK clock edge		12	—	ns
t_{HDSPI}	SPI_SCK	SPI_SI	Hold time on SPI_SI after the rising SPI_SCK clock edge		12	—	ns
t_{SPISCKH}	SPI_SCK	SPI_SCK	SPI_SCK clock High time		20	—	ns
t_{SPISCKL}	SPI_SCK	SPI_SCK	SPI_SCK clock Low time		20	—	ns
t_{SPISCKCYC}	SPI_SCK	SPI_SCK	SPI_SCK clock period*		40	1,000	ns
f_{SPI_SCK}	SPI_SCK	SPI_SCK	Sustained SPI_SCK clock frequency*		1	25	MHz

* = Applies after sending the synchronization pattern.

Power Consumption Characteristics

Core Power

Table 61 shows the power consumed on the internal VCC supply rail when the device is filled with 16-bit binary counters, measured with a 32.768 kHz and at 32.0 MHz. Low power (–L) at 1.0 V operation and high-performance (–T) version at 1.2V operation is provided.

Table 61: VCC Power Consumption for Device Filled with 16-Bit Binary Counters

Symbol	Description	Grade	VCC	iCE65L01		iCE65L04		iCE65L08		Units
				Typical	Max.	Typical	Max.	Typical	Max.	
I_{CC0K}	f = 0,	–L	1.0V	12		26		54		µA
		–T	1.2V	19		43		90		
I_{CC32K}	f ≤ 32.768 kHz	–L	1.0V	15		31		62		µA
		–T	1.2V	23		50		100		
I_{CC32M}	f = 32.0 MHz	–L	1.0V	3		7		14		mA
		–T	1.2V	4		8		17		

I/O Power

Table 62 provides the static current by I/O bank. The typical current for I/O Banks 0, 1, 2 and the SPI bank is not measurable within the accuracy of the test environment. The PIOs in I/O Bank 3 use different circuitry and dissipate a small amount of static current.

Table 62: I/O Bank Static Current (f = 0 MHz)

Symbol	Description		Typical	Max	Units
I_{CC0 0}	I/O Bank 0	Static current consumption per I/O bank. f = 0 MHz. No PIO pull-up resistors enabled. All inputs grounded. All outputs driving Low.	« 1		µA
I_{CC0 1}	I/O Bank 1		« 1		µA
I_{CC0 2}	I/O Bank 2		« 1		µA
I_{CC0_3}	I/O Bank 3		iCE65L01: « 1 iCE65L04/08: 1.2		µA
I_{CC0_SPI}	SPI Bank		« 1		µA

NOTE: The typical static current for I/O Banks 0, 1, 2, and the SPI bank is less than the accuracy of the device tester.

Power Estimator

To estimate the power consumption for a specific application, please download and use the iCE65 Power Estimator Spreadsheet or use the power estimator built into the iCEcube software.

■ iCE65 Power Estimator Spreadsheet